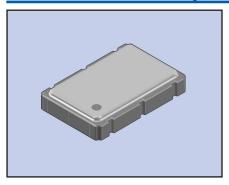
ECS-VXO-73/VXO-75 SERIES SMD VCXO'S





The ECS-VXO-73 (3.3V) and ECS-VXO-75 (5.0V) are miniature VCXO'S voltage controlled crystal oscillators with tri-state in a ceramic SMD package. The low profile package is ideal for todays advanced portable PC and instrumentation applications.

FEATURES

- 3.3V & 5.0V versions
- 1.6 mm profile
- Low power consumption
- Tri-State
- Seam welded package
- Tape & Reel (1,000 pcs STD)
- PbFree/RoHS Compliant



PART NUMBERING GUIDE

SERIES		FREQUENCY (27.0 MHz)
ECS-VXO-73	_	270

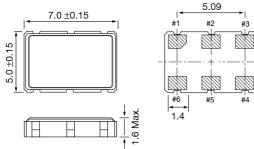
Sample Part Number: ECS-VXO-73-270. 3.3V. 27.000 MHz VCXO

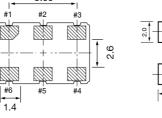
OPERATING CONDITIONS/ELECTRICAL CHARACTERISTICS

DADAMETERO	CONDITIONS	ECS-VXO-73 (3.3V)			ECS-VXO-75 (5.0V)			UNITO
PARAMETERS		MIN	TYP	MAX	MIN	TYP	MAX	- UNITS
FREQUENCY RANGE		3.000		77.760	3.000		77.760	MHz
TEMPERATURE RANGE	Operating	-10		+70	-10		+70	°C
TEMPERATURE RANGE	Storage	-40		+85	-40		+85	°C
SUPPLY VOLTAGE	+3.14	+3.3	+3.465	+4.75	+5.0	+5.25	V DC	
FREQUENCY STABILITY*	All Conditions			±50			±50	PPM
FREQUENCY PULLING RANGE		±90			±100			PPM
CONTROL VOLTAGE		0	+1.65	+3.3	+0.5	+2.5	+4.5	V DC
FREQUENCY LINEARITY	Positive Slope			±15			±10	%
INPUT CURRENT	No Load			20			40	mA
OUTPUT SYMMETRY	@ 1/2 VCC Level	40/60		60/40	40/60		60/40	%
RISE AND FALL TIMES				5			5	ns
LOGIC "0" LEVEL				10% Vcc			10% Vcc	V DC
LOGIC "1" LEVEL		90% Vcc			90% Vcc			V DC
LOAD	CMOS			15			15	pF
START-UP TIME				10			10	ms
MODULATION BANDWIDTH	(-3 dB)	10			10			KHz
DISABLE TIME				100			100	ns

^{*} Inclusive of 25°C tolerance, operating temperature range, input voltage change, load change, aging shock and vibration.

PACKAGE DIMENSIONS (mm)





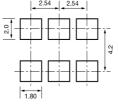


Figure 1) ECS-VXO-73/VXO-75 Top and Side view

Figure 2) Land Pattern

PIN CONNECTIONS					
#1	V CONTROL				
#2	TRI-STATE				
#3	GND				
#4	OUTPUT				
#5	NC				
#6	Vcc				

ECS-VXO-73/VXO-75 TRI-STATE CONTROL VOLTAGE						
VXO-73, PA	D 2 VXO-75, F	PAD 2 PAD 4				
OPEN	OPEN	OSCILLATION				
+2.2V MIN	+3.5V MIN	N OSCILLATION				
+0.8V MIN	+1.5V MIN	N HIGH				

Note: A 0.01-0.1 µF bypass capacitor should be placed between Vcc (Pad 6) and GND (Pad 3) for stable oscillation and to minimize power line noise.